BLS8G2731L-400P; BLS8G2731LS-400P LDMOS S-band radar power transistor

AMPLEON

Rev. 2 — 1 September 2015

Product data sheet

Product profile 1.

1.1 General description

400 W LDMOS power transistor for S-band radar applications in the frequency range from 2.7 GHz to 3.1 GHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25$ °C; $t_p = 50 \mu s$; $\delta = 2$ %; $I_{Dq} = 200$ mA; in a class-AB demo test circuit.

Test signal	f	V _{DS}	P _{L(1dB)}	G _p [1]	η _D [1]	P _{L(2dB)}	G _p [2]	η _D [2]
	(GHz)	(V)	(W)	(dB)	(%)	(W)	(dB)	(%)
pulsed RF	2.7 to 2.9	32	540	11	45	610	10	46
	2.9 to 3.1	32	490	12	47	550	11	49
	2.7 to 3.1	32	530	12	45	590	11	47

^[1] at 1 dB gain compression.

1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for S-band operation
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

S-band radar applications in the frequent range 2.7 GHz to 3.1 GHz

^[2] at 2 dB gain compression.

2. Pinning information

Table 2. Pinning

Pin	Description	Sim	plified outline	Graphic symbol
BLS8G273	1L-400P (SOT539A)			
1	drain1			_
2	drain2		1 2	
3	gate1	2	5	
4	gate2		3 4	3 - 5
5	source	[1]		4
				<u>'</u>
				2 sym117
BLS8G273	1LS-400P (SOT539B)			
1	drain1			
2	drain2		1 2	1
3	gate1		5	
4	gate2		3 4	3 - 5
5	source	[1]		4
				'
				2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BLS8G2731L-400P		flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A		
BLS8G2731LS-400P	-	earless flanged balanced ceramic package; 4 leads	SOT539B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-6	+11	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C

Continuous use at maximum temperature will affect the reliability. For details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
Z _{th(j-mb)}	transient thermal impedance from junction	T _{case} = 85 °C; P _L = 400 W		
	to mounting base	t_p = 100 μ s; δ = 10 %	0.067	K/W
		t_p = 200 μ s; δ = 10 %	0.083	K/W
		t_p = 300 μ s; δ = 10 %	0.091	K/W
		t_p = 100 μ s; δ = 20 %	0.082	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 3 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 300 \text{ mA}$	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	2.8	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	51	-	Α
I_{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	280	nA
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_{D} = 15.0 \text{ A}$	-	21	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 10.5 A$	-	0.058	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF; f = 3.1 GHz; t_p = 300 μ s; δ = 10 %; RF performance at V_{DS} = 32 V; I_{Dq} = 200 mA; T_{case} = 25 $^{\circ}$ C; unless otherwise specified, in a class-AB narrow band production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _L = 400 W	10.3	13	-	dB
η_{D}	drain efficiency	P _L = 400 W	43	47	-	%
RLin	input return loss	P _L = 400 W	-	-8	-	dB
P _{droop(pulse)}	pulse droop power	P _L = 400 W	-	0	0.5	dB
t _r	rise time	P _L = 400 W	-	5	50	ns
t _f	fall time	P _L = 400 W	-	5	50	ns
P _{L(2dB)}	output power at 2 dB gain compression		400	-	-	W

7. Test information

7.1 Ruggedness in class-AB operation

The BLS8G2731L-400P and BLS8G2731LS-400P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 200 mA; P_L = 400 W; t_p = 300 μ s; δ = 10 %.

7.2 Impedance information

Table 8. Typical impedance

f	Z _S [1]	Z _L [1]
(GHz)	(Ω)	(Ω)
2.7	1.0 – 7.0j	1.8 – 4.9j
2.9	1.5 – 8.5j	2.5 – 5.2j
3.1	4.0 – 9.0j	3.6 – 4.7j

[1] Impedances are taken at a single halve of the push-pull transistor

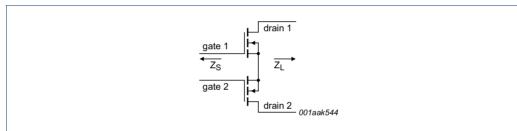


Fig 1. Definition of transistor impedance

7.3 Test circuit

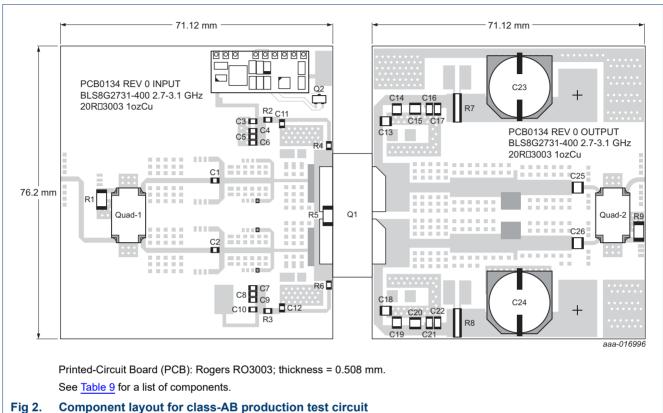


Table 9. List of components

For test circuit see Figure 2.

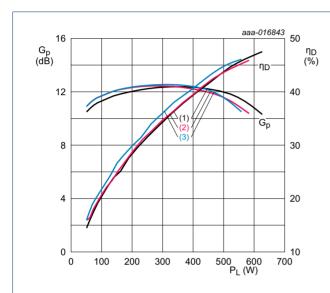
Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	5.6 pF	ATC: ATC600F5R6
C3, C10	multilayer ceramic chip capacitor	220 pF, 50 V	Murata: GRM2165C1H221JA01D
C4, C9	multilayer ceramic chip capacitor	10 nF, 50 V	Murata: GRM216R71H103KA01D
C5, C8	multilayer ceramic chip capacitor	100 nF, 50 V	Murata: GRM21BR71H104KA01L
C6, C7	multilayer ceramic chip capacitor	10 μF, 10 V	Murata: GRM21BR61A106KE19L
C11, C12	multilayer ceramic chip capacitor	15 pF	ATC: ATC600F150
C13, C14, C18, C19, C25, C26	multilayer ceramic chip capacitor	22 pF	Passive Plus: 1111N220GW501
C15, C20	electrolytic capacitor	560 pF	Passive Plus: 1111N561GW501
C16, C21	multilayer ceramic chip capacitor	0.01 μF, 250 V	Murata: GRM31B7U2E103JW31L
C17,C22	multilayer ceramic chip capacitor	0.1 μF, 250 V	Murata: GRM32DR72E104KW01L
C23, C24	electrolytic capacitor	470 μF, 63 V	Panasonic: EEV-TG1J471M
R1, R9	resistor	50 Ω	EMC: SMT2010TALN
R2, R3	shunt resistor	9.1 Ω	Vishay Dale: CRCW08059R10FKEA
R4, R6	shunt resistor	5.1 Ω	Vishay Dale: CRCW08055R10FKEA
R5	shunt resistor	510 Ω	Vishay Dale: CRCW2010510RFKEFHP
R7, R8	resistor	0.01 Ω	Susumu: RL7520WT-R010-F

Table 9. List of components ... continued

For test circuit see Figure 2.

Component	Description	Value	Remarks
Q1	transistor	-	Ampleon: BLS8G2731LS-400P
Q2	transistor	-	NXP: MMBT2222A
Quad-1, Quad-2	90 degree hybrid coupler	-	Innovative Power Products: IPP-7075

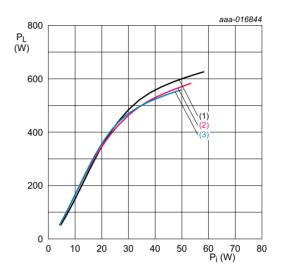
7.4 Graphical data



 V_{DS} = 32 V; I_{Dq} = 200 mA; t_p = 100 $\mu s;$ δ = 2 %.

- (1) f = 2700 MHz
- (2) f = 2900 MHz
- (3) f = 3100 MHz

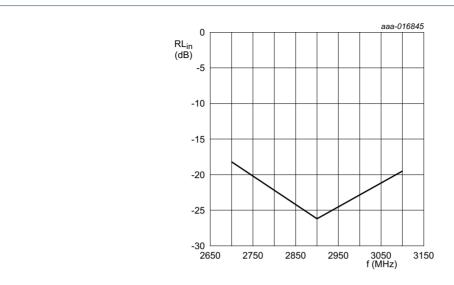
Fig 3. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; t_p = 100 $\mu s;$ δ = 2 %.

- (1) f = 2700 MHz
- (2) f = 2900 MHz
- (3) f = 3100 MHz

Fig 4. Output power as a function of input power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; P_i = 10 dBm.

Fig 5. Input return loss as a function of frequency; typical values

8. Package outline

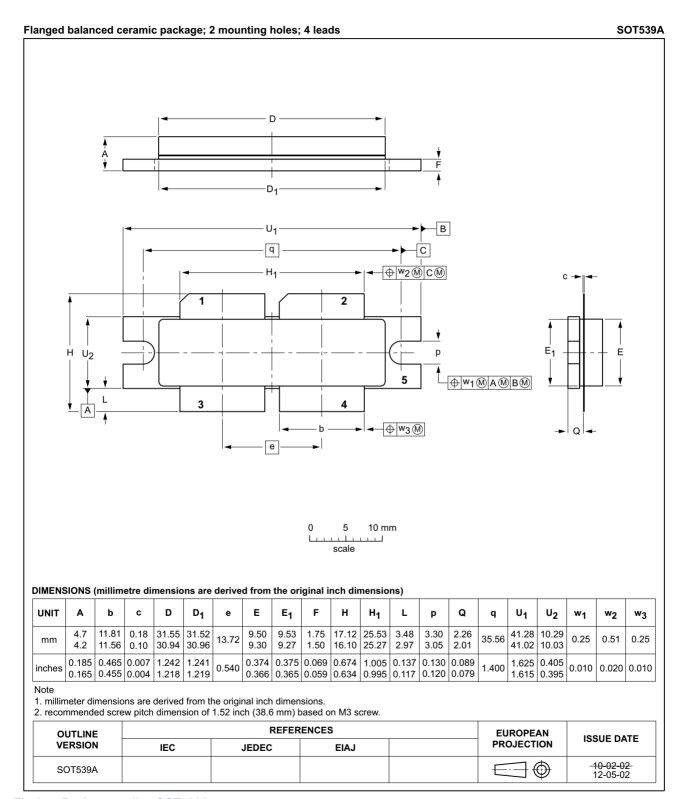


Fig 6. Package outline SOT539A

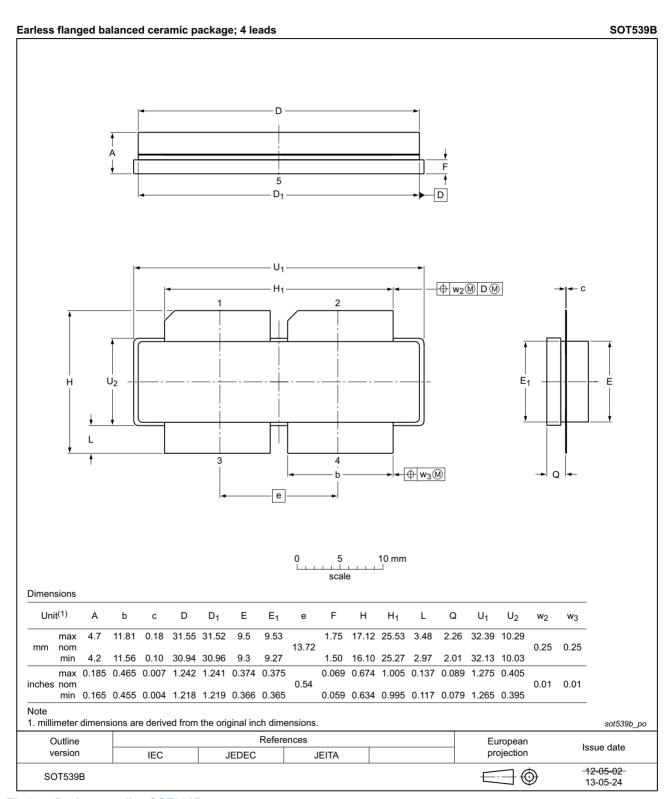


Fig 7. Package outline SOT539B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
S-band	Short wave Band
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS8G2731L-400P_LS-400P#2	20150901	Product data sheet		BLS8G2731L-400P_LS-400P v.1
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.			
	Legal texts have been adapted to the new company name where appropriate.			ny name where appropriate.
BLS8G2731L-400P_LS-400P v.1	20150526	Product data sheet	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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BLS8G2731L(S)-400P

LDMOS S-band radar power transistor

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LDMOS S-band radar power transistor

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